

Supplement – High field superconducting properties of Ba(Fe_{1-x}Co_x)₂As₂ thin films

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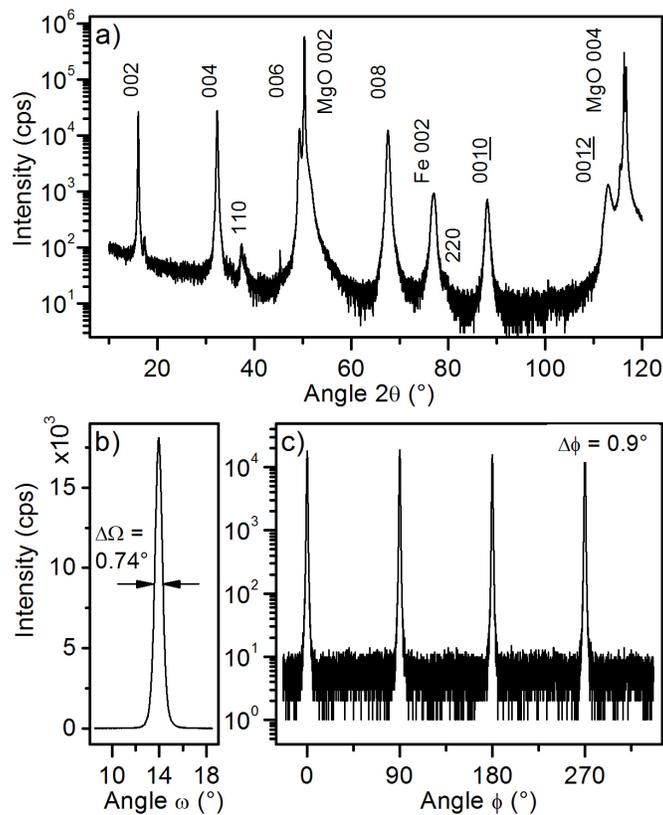


Figure S1. X-ray diffraction of the Ba-122/Fe/MgO sample: a) θ - 2θ scan showing mainly c -axis orientation of Fe and Co-doped Ba-122 and a small component of the Co-doped Ba-122 (110) orientation, b) Co-doped Ba-122 (004) rocking curve, c) Co-doped Ba-122 (103) ϕ scan.

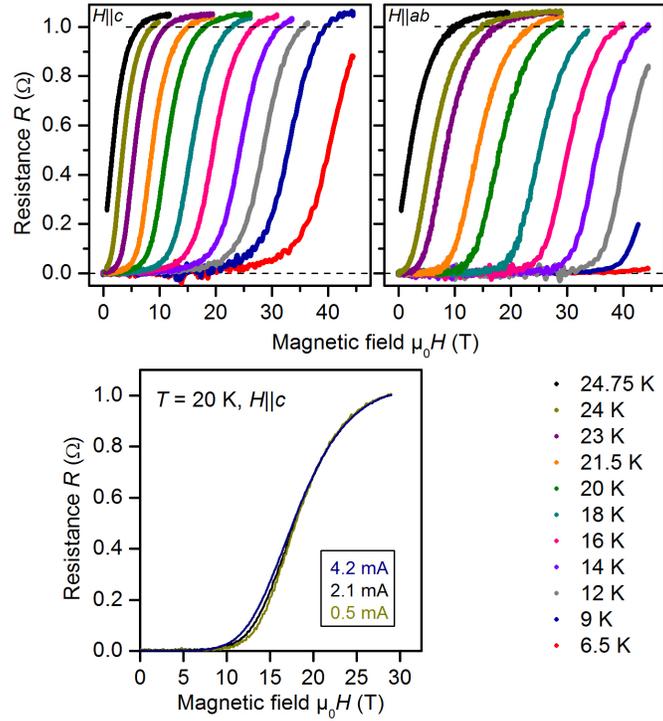


Figure S2. Field dependence of the resistance R for both major crystallographic directions, $H||c$ and $H||ab$, measured at the IFW Dresden pulsed field facility. The current test at 20 K, $H||c$ (below) showed no heating effects. Differences below midpoint of transition are due to flux motion and correspond to the $J_c(H)$ dependence in the vicinity of H_{irr} ($0.5 \text{ mA} \approx 300 \text{ A/cm}^2$).

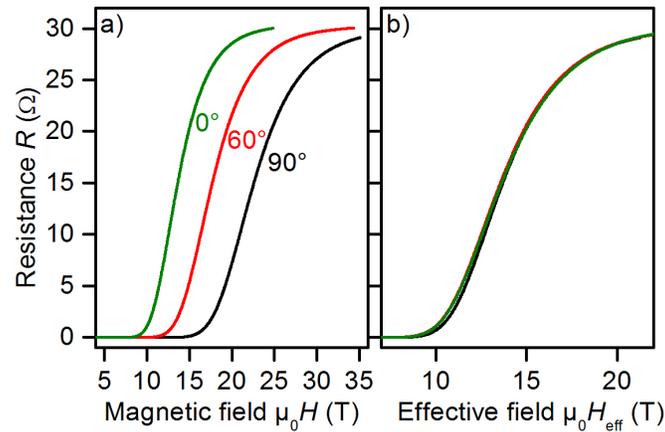


Figure S3. a) Magnetic field dependence of the resistive transition for three field orientations, b) Scaling of $R(H)$ according to $H_{eff}(\theta) = H \cdot F(\theta)$ (Eq. 2) with $\delta = 1.77$. Above midpoint of transition, the scaling is criterion- independent, showing that our trial function describes the H_{c2} dependency. Deviations below midpoint are due to correlated pinning and a differing H_{irr} dependency.